



Features:

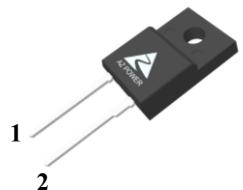
- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

Benefits:

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

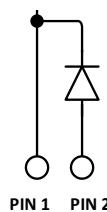
Symbol	Value	Unit
V_{RRM}	650	V
I_F (T_C=133°C)	10	A
Q_C	38	nC

Outline



TO-220-2FP

Circuit



Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	T _J = 25°C
V_{RRM}	Repetitive Peak Reverse	650	V	T _J = 25°C
V_{RSM}	Surge Peak Reverse Voltage	650	V	T _J = 25°C
I_F	Continuous Forward Current	22 17.5 10	A	T _C = 25°C T _C = 75°C T _C = 133°C
I_{FRM}	Repetitive Peak Forward Surge Current	51 46	A	T _C = 25°C, T _P = 10ms, Half Sine Wave T _C = 110°C, T _P = 10ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	67 61	A	T _C = 25°C, T _P = 10ms, Half Sine Wave T _C = 110°C, T _P = 10ms, Half Sine Wave
P_D	Power Dissipation	60 26	W	T _C = 25°C T _C = 110°C
T_{J,max}	Operating Junction Temperature	175	°C	
T_{stg}	Storage Temperature Range	-55 to 175	°C	



Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
R_{thJC}	Thermal resistance		2.5		°C/W

Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
V_{DC}	DC Blocking Voltage	650			V	$I_R = 100\mu A, T_J = 25^\circ C$
V_F	Forward Voltage		1.35 1.65	1.6 2.0	V	$I_F = 10A, T_J = 25^\circ C$ $I_F = 10A, T_J = 175^\circ C$
I_R	Reverse Current		2 10	50 200	μA	$V_R = 650V, T_J = 25^\circ C$ $V_R = 650V, T_J = 175^\circ C$
Q_C	Total Capacitive Charge		38		nC	$I_F = 10A, dI/dt = 300A/\mu s$ $T_J = 25^\circ C, V_R = 400V$
C	Total Capacitance		683 88 82		pF	$V_R = 1V, T_J = 25^\circ C, f = 1 \text{ MHz}$ $V_R = 200V, T_J = 25^\circ C, f = 1 \text{ MHz}$ $V_R = 400V, T_J = 25^\circ C, f = 1 \text{ MHz}$

Typical Performance

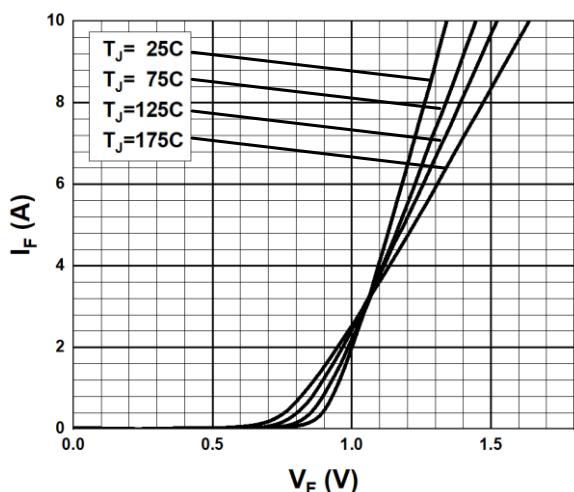


Fig. 1 Forward Characteristics

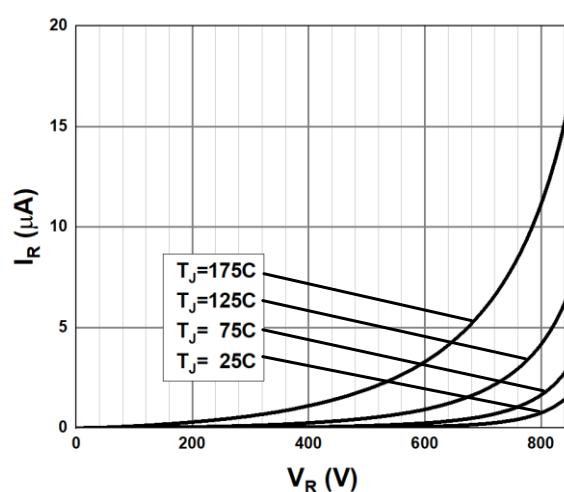


Fig. 2 Reverse Characteristics



Typical Performance

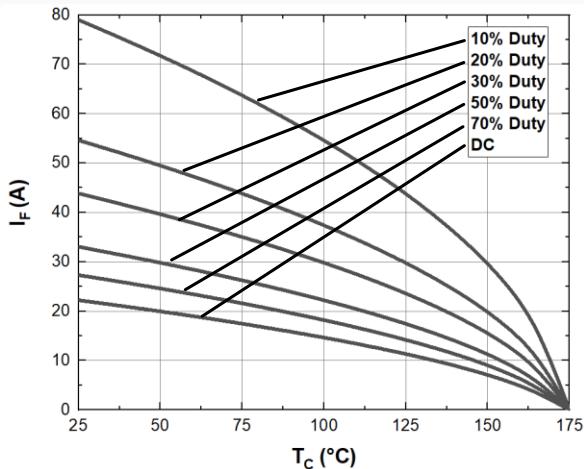


Fig. 3 Current Derating

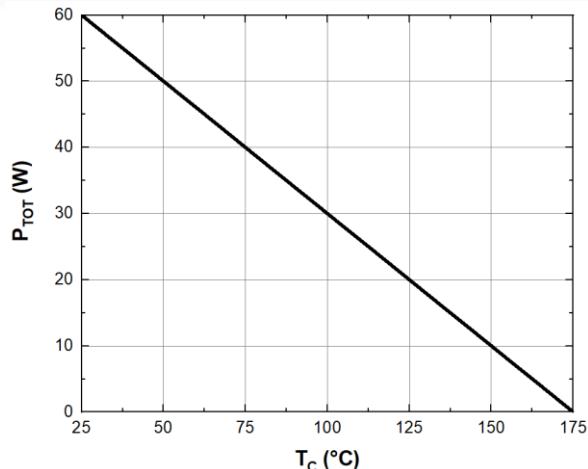


Fig. 4 Power Derating

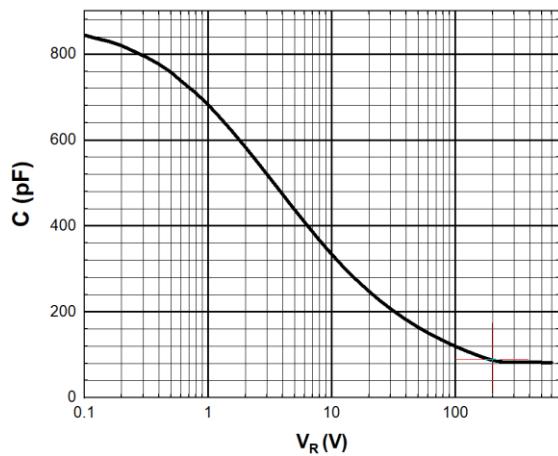


Fig. 5 Capacitance vs. Reverse Voltage

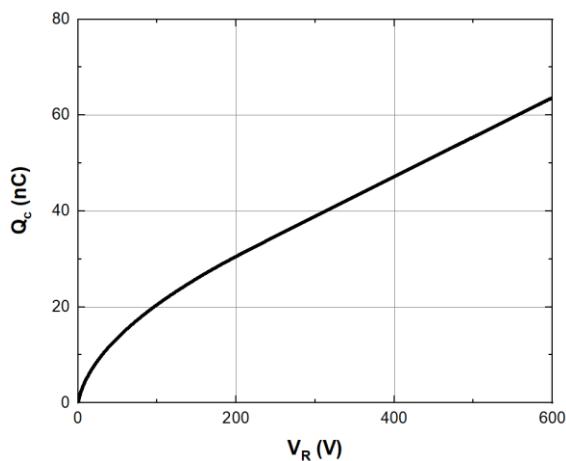


Fig. 6 Recovery Charge vs. Reverse Voltage

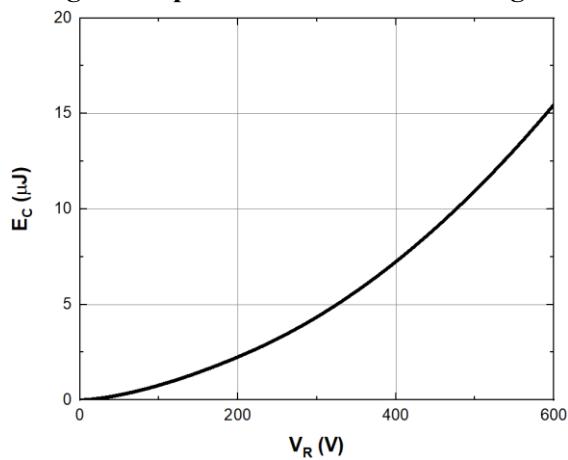


Fig. 7 Capacitance stored Energy

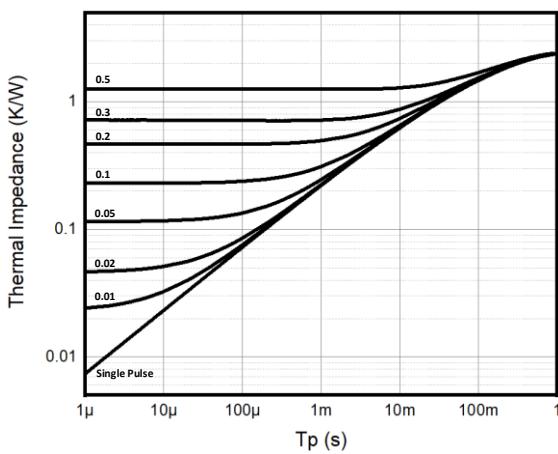
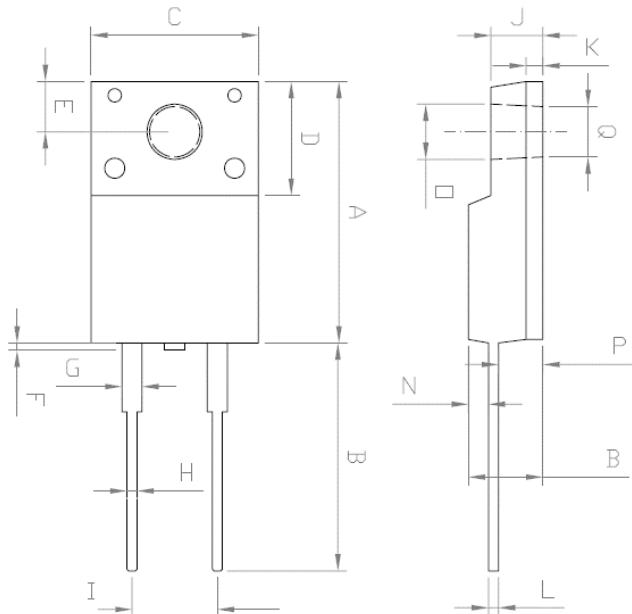


Fig. 8 Thermal Impedance



Package TO-220-2FP (Unit: mm)



REF.DIM	DATA BOOK mm		
	NOR	MIN	MAX
A	15.6	14.8	16.1
B	13	12.65	13.8
C	10	9.85	10.36
D	6.5	4.6	6.8
E	3.0	2.55	3.5
F			1
G	1.2	1	1.45
H	0.6	0.3	0.9
I	5.1	4.8	5.4
J	3.1	2.34	3.3
K	1.0	0.55	1.3
L	0.6	0.36	0.8
M	4.45	4.2	4.9
N	1.2	1.1	1.8
O	3.3	2.9	3.5
P	2.6	2.5	3.15
Q	3	2.9	3.5

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